

Inductive Proximity Sensor

Explanation to terms

p	i to terms		
Terms	Explanations	Terms	Explanations
Inductive distance (Rating)	Indicated as below, it is the distance from the sensor to the point (maximum inductive distance) which is just detected when the standard detected object approaches slowly to the inductive part of the approach sensor. For example JM12L-F2NK Standard detected object (Iron 12×12×1mm) Maximum inductive distances of all of the products are at the range of 2.7-3.3mm	Difference	When the standard detected object approaches the sensor along the inductive axis. it is the difference between the initial distance (action distance) and the distance leaving to beyond and just reset (reset distance). It is presented by the ratio (% to the action distance. The difference should be remained in 10-20%. rated distance generally in order to prevent against the output skip caused by the vibration of the detected object. **Reset distance** Action distance** **Inductive axis**
	The distance at which the sensor is capable of stable detecting after taking into consideration of the ambient		The deviation of action positions is resulted when the sensor repeats inducting under certain conditions The accuracy of repetition of vertical
Inductive distance (Actual)	temperature, variation of supply voltage. and so on factors (In general, it is 70%-80% of rated inductive distance) Used at the set distances: 0-24mm. For example JM12L-F2NK Standard detected object (Iron 12×12×11mm)	Accuracy of repetition	direction to inductive axis The accuracy of repetition of inductive axis It is indicated as below that the standard detected objects are
			attached to the rotating plate by the specified spacing distance and then placed right ahead to the proximity sensor. Have the plate rotated while the output of the sensor is made sure, then the maximum inductive times of stable output per minute are obtained. Standard detected object
	The smallest detected object within the certain inductive distance. The inductive distance, differences, and so on specifications and characteristics are made according to the standard detected object. The standard detected object is made of iron (aluminium for plain metal proximity sensor and selective metal proximity sensor) Dimension of standard detected object (aXamm) flash (Scaled). similar to the size of the detecting part(b) Non-flash (Non-scaled)about 1.5 times of the size of the detecting part(b).	Maximum response frequency	Proximity sensor 75% inductive distance a: Length of side of standard detected object when the sensor is at the set distance, the standard detected object approaches it from the right or the left respectively. The diagram presents the locus composed of the position points at which the sensor operates. (With the sensitivity button at the highest sensitive status) The diagram is for determination of the installation position of the sensor. Actual operation may results deviation. Standard detected object
Standard inducted object	Size of the detected object Characteristics of inductive distance Light 1 11mm Light 1 11mm Light 1 11mm Light 1 11mm Length of side of the detected object(mm)	Frequency of detecting field	It indicates how the inductive distance is influenced by the size of the detected object. The sensitivity of the sensor provided with a sensitivity button should be adjusted for exact inducting. Characteristics of correspondent positions of the maximum inductive distance of the detected object are for determination of the stable inductive distance, which is correspondent to the size of the detected object. (Note: The diagram is only an example. Actual operation may results
	Proximity sensor A Detected object	Size of detected odject characteris- tics of inductive distance	deviation.) For example:JM18L-F5NK Detected object Sensor Length of side of the detected object a(mm)



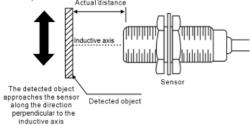
Inductive Proximity Sensor

Attentions to operation:

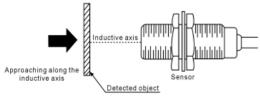
Setting of distance

When the detected object approaches the sensor perpendicularly along the inductive axis.

The method that the detected object approaches to the sensor perpendicularly along the inductive axis is usually adopted. The distance between the sensor head and the detected object should be regulated to slightly shorter than the set distance (actual distance) of rated inductive distance.



When the detected object approaches the sensor along the inductive axis When adopting the method that the detected object approaches the sensor along the inductive axis the inducting may be done by the rated inductive distance (Max. In ductive distance). But it shall be noted that danger will occur by the bump caused by the detected object and proximity sensor because of the moving speed or others.



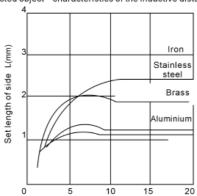
The metal category and inductive distance

The inductive distance is the relative value of the standard detected object. If the sensor is smaller than the detected object or is nonmetallic, the inductive distance will be relatively shortened.

It may be sensed by the equidistance if the plain metal approach sensor is not affected by the materials used.

The iron magnetic body can not be sensed by the selective metal approach sensor, except the aluminum and copper nonmagnetic body.

Size of the detected object -- characteristics of the inductive distance



The length of one of sides of the detected object a(mm)

The correction parameter of materials used in the detected object

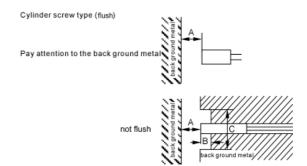
Detected object	Correction parameter
Iron	10
Stainless steel (SU304)	About 0.76
Brass	About 0.5
Aluminium	About 0.48

In addition.it shall be noted that the inductive distance will be changed it the detected object is plated.

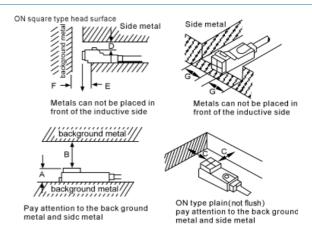
Installation

The influence to the sensor made by the ambient metal

The sensor will be affected if there are metals around the approach sensor. With the special positions between the metal and the sensor, keep the specified distance between them according to the requirement. For the details, please refer to the product brochure (the correct operation method).

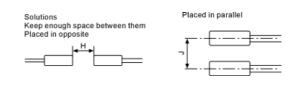


Pay attention to the background metal and the metal around the Plunger

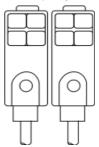


Mutual interference

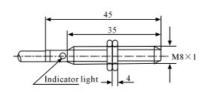
When proximity sensors are placed closely to each other in the state of rest. the high frequency magnetic field created by one proximity sensor will affect the electromagnetism to another, which will lead unsteady operation to each other (That is mutual interference)

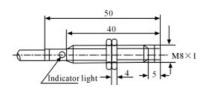


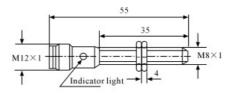
For the details, please refer to the product brochure (the correct operation methods) Two sets of sensors can be used closely provided that the frequency type and oscillation frequency are different.

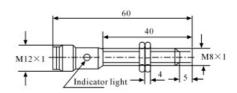








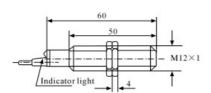


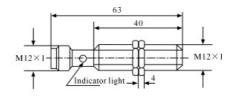


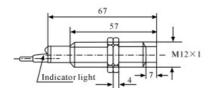
Detected Distance Sn		etected Distance Sn	1mm	2mm	1mm	2mm	
Setting Distance Sn			0-0.8mm	0-1.6mm	0-0.8mm	0-1.6mm	
St	andar	d Detected Object A3 Steel	$6 \times 6 \times 1 \text{mm}^3$	$6 \times 6 \times 1$ mm 3	$6 \times 6 \times 1$ mm 3	$6 \times 6 \times 1$ mm 3	
		Installation Mode	Flush Type	Not flush Type	Flush Type	Not flush Type	
		NO	JM8L-F1NK	JM8L-Y2NK	JM8L-F1NKE	JM8L-Y2NKE	
	NPN	NC	JM8L-F1NB	JM8L-Y2NB	JM8L-F1NBE	JM8L-Y2NBE	
		NO/NC					
DC		NO	JM8L-F1PK	JM8L-Y2PK	JM8L-F1PKE	JM8L-Y2PKE	
power	PNP	NC	JM8L-F1PB	JM8L-Y2PB	JM8L-F1PBE	JM8L-Y2PBE	
		NO/NC					
		Two-wire system NO	JM8L-F1TK	JM8L-Y2TK	JM8L-F1TKE	JM8L-Y2TKE	
		Two-wire system NC	JM8L-F1TB	JM8L-Y2TB	JM8L-F1TBE	JM8L-Y2TBE	
		Two-wire system NO					
AC ower		Two-wire system NC					
		Three-wire system NO/NC					
		Supply voltage	DC10-30V				
	C	Current consumption	NPN/PNP Transistor 1015mA,DC two-wire ≤ 0.8mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA				
	(Output voltage drop	NPN/PNP Transistor ≤ 1.5V,DC two-wire ≤ 7V				
	R	esponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz				
Detected objection			Metal				
Housing material			Brass, nickel-plated				
Ambient temperature			-25~70 ℃				
	li	nsulation resistance	\geqslant 30M Ω				
		Protection degree		IP	67		

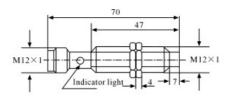


JM12L Inductive Proximity Sensor





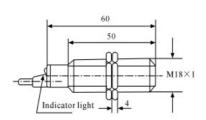


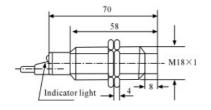


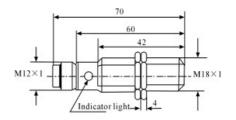
Detected Distance Sn		etected Distance Sn	2mm	4mm	2mm	4mm	
Setting Distance Sn			0-1.6mm	0-3.2mm	0-1.6mm	0-3.2mm	
	Stanc	dard Detected A3 Steel	$12 \times 12 \times 1 \text{mm}^3$	$12 \times 12 \times 1 \text{mm}^3$	$12 \times 12 \times 1 \text{mm}^3$	$12 \times 12 \times 1 \text{mm}^3$	
		Installation mode	Flush Type	Not flush Type	Flush Type	Not flush Type	
		NO	JM12L-F2NK	JM12L-Y4NK	JM12L-F2NKE	JM12L-Y4NKE	
	NPN	NC	JM12L-F2NB	JM12L-Y4NB	JM12L-F2NBE	JM12L-Y4NBE	
		NO/NC	JM12L-F2NH	JM12L-Y4NH	JM12L-F2NHE	JM12L-Y4NHE	
DC		NO	JM12L-F2PK	JM12L-Y4PK	JM12L-F2PKE	JM12L-Y4PKE	
ower	PNP	NC	JM12L-F2PB	JM12L-Y4PB	JM12L-F2PBE	JM12L-Y4PBE	
		NO/NC	JM12L-F2PH	JM12L-Y4PH	JM12L-F2PHE	JM12L-Y4PHE	
		Two-wire system NO	JM12L-F2TK	JM12L-Y4TK	JM12L-F2TKE	JM12L-Y4TKE	
		Two-wire system NC	JM12L-F2TB	JM12L-Y4TB	JM12L-F2TBE	JM12L-Y4TBE	
		Two-wire system NO	JM12L-F2AK	JM12L-Y4AK	JM12L-F2AKE	JM12L-Y4AKE	
AC ower	Two-wire system NC		JM12L-F2AB	JM12L-Y4AB	JM12L-F2ABE	JM12L-Y4ABE	
	Thr	ree-wire System Open/Close					
		Supply voltage	DC10-30V AC90-250V				
	Cı	urrent consumption	NPN/PNP Transistor 1015mA,DC two-wire \leqslant 0.8mA,AC \leqslant 2mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	0	Output voltage drop	NPN/PNP Transistor ≤ 1.5V,DC two-wire ≤ 7V,AC ≤ 8V				
	Re	esponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1015Hz				
Detected object			Metal				
Housing material			Metal				
Ambient temperature			-25~70℃				
	In	sulation resistance	\geqslant 30M Ω above				
	I	Protection degree		IPe	67		

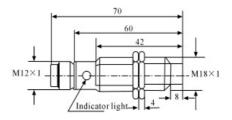


JM18L Inductive Proximity Sensor





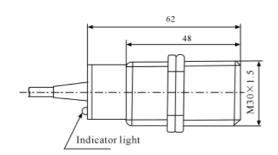


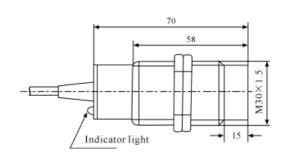


Detected Distance Sn		etected Distance Sn	5mm	8mm	5mm	8mm	
Setting Distance Sn			0-1.6mm	0-6.4mm	0-4mm	0-6.4mm	
	Stand	dard Detected A3 Steel	$24 \times 24 \times 1 \text{mm}^3$	$24 \times 24 \times 1 \text{mm}^3$	$24 \times 24 \times 1 \text{mm}^3$	$24 \times 24 \times 1 \text{mm}^3$	
		Installation mode	Flush Type	Not flush Type	Flush Type	Not flush Type	
		NO	JM18L-F5NK	JM18L-Y8NK	JM18L-F5NKE	JM18L-Y8NKE	
	NPN	NC	JM18L-F5NB	JM18L-Y8NB	JM18L-F5NBE	JM18L-Y8NBE	
		NO/NC	JM18L-F5NH	JM18L-Y8NH	JM18L-F5NHE	JM18L-Y8NBE	
DC		NO	JM18L-F5PK	JM18L-Y8PK	JM18L-F5PKE	JM18L-Y8PKE	
oower	PNP	NC	JM18L-F5PB	JM18L-Y8PB	JM18L-F5PBE	JM18L-Y8PBE	
		NO/NC	JM18L-F5PH	JM18L-Y8PH	JM18L-F5PHE	JM18L-Y8PHE	
		Two-wire system NO	JM18L-F5TK	JM18L-Y8TK	JM18L-F5TKE	JM18L-Y8TKE	
	Two-wire system NC		JM18L-F5TB	JM18L-Y8TB	JM18L-F5TBE	JM18L-Y8TBE	
		Two-wire system NO	JM18L-F5AK	JM18L-Y8AK	JM18L-F5AKE	JM18L-Y8AKE	
AC oower	Two-wire system NC		JM18L-F5AB	JM18L-Y8AB	JM18L-F5ABE	JM18L-Y8ABE	
	Three-wire System Open/Close						
		Supply voltage	DC10-30V AC90-250V				
	C	urrent consumption	NPN/PNP Transistor 1015mA,DC two-wire ≤ 0.8 mA,AC ≤ 2 mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	С	Output voltage drop	NPN/PNP Transistor \leq 1.5V,DC two-wire \leq 7V,AC \leq 8V				
	R	esponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1015Hz				
Detected object			Metal				
Housing material			ABS Resin/Metal				
Ambient temperature			-25~70°C				
	In	sulation resistance	\geqslant 30M Ω above				
		Protection degree		IP	67		



JM30L Inductive Proximity Sensor

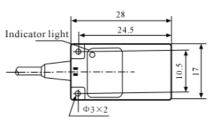




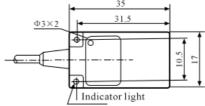
Detected Distance Sn		etected Distance Sn	10mm	15mm	5mm	15mm	
Setting Distance Sn			0-8mm	0-12mm	0-4mm	0-12mm	
	Stan	dard Detected A3 Steel	$45\times45\times1\text{mm}^3$	$45 \times 45 \times 1 \mathrm{mm}^3$	$24 \times 24 \times 1 \text{mm}^3$	$45 \times 45 \times 1 \text{mm}^3$	
		Installation mode	Flush Type	Not flush Type	Flush Type	Not flush Type	
		NO	JM30L-F10NK	JM30L-Y15NK	JM30L-F10NKE	JM30L-Y15NKE	
	NPN	NC	JM30L-F10NB	JM30L-Y15NB	JM30L-F10NBE	JM30L-Y15NBE	
		NO/NC	JM30L-F10NH	JM30L-Y15NH	JM30L-F10NHE	JM30L-Y15NKE	
DC		NO	JM30L-F10PK	JM30L-Y15PK	JM30L-F10PKE	JM30L-Y15PKE	
oower	PNP	NC	JM30L-F10PB	JM30L-Y15PB	JM30L-F10PBE	JM30L-Y15PBE	
		NO/NC	JM30L-F10PH	JM30L-Y15PH	JM30L-F10PHE	JM30L-Y15PHE	
	Two-wire system NO		JM30L-F10TK	JM30L-Y15TK	JM30L-F10TKE	JM30L-Y15TKE	
	Two-wire system NC		JM30L-F10TB	JM30L-Y15TB	JM30L-F10TBE	JM30L-Y15TBE	
		Two-wire system NO	JM30L-F10AK	JM30L-Y15AK	JM30L-F10AKE	JM30L-Y15AKE	
AC power		Two-wire system NC	JM30L-F10AB	JM30L-Y15AB	JM30L-F10ABE	JM30L-Y15ABE	
	Three-wire System Open/Close						
		Supply voltage	DC10-30V AC90-250V				
	C	Current consumption	NPN/PNP Transistor 1015mA,DC two-wire \leqslant 0.8mA,AC \leqslant 2mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	(Output voltage drop	NPN/PNP Transistor \leqslant 1.5V,DC two-wire \leqslant 7V,AC \leqslant 8V				
	R	desponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1020Hz				
Detected object			Metal				
Housing material			ABS Resin/Metal				
	Α	mbient temperature	-25~70℃				
	lı	nsulation resistance	≥30M Ω				
		Protection degree		IP®	67		



JG17L/JG17L-L Inductive Proximity Sensor





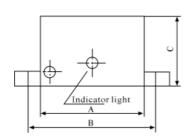


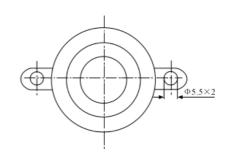


	Detected Distance Sn		5mm		5mm		
	S	Setting Distance Sn	0-4.2mm		0-4.2mm		
	Stand	dard Detected A3 Steel	$17\times17\times1\text{mm}^3$		$17 \times 17 \times 1 \text{mm}^3$		
		Installation mode	Not flush Type		Not flush Type		
		NO	JG17L-F5NK		JG17L-F5NKL		
	NPN	NC	JG17L-F5NB		JG17L-F5NBL		
		NO/NC					
DC		NO	JG17L-F5PK		JG17L-F5PKL		
power	PNP	NC	JG17L-F5PB		JG17L-F5PBL		
		NO/NC					
		Two-wire system NO	JG17L-F5TK		JG17L-F5TKL		
		Two-wire system NC	JG17L-F5TB		JG17L-F5TBL		
		Two-wire system NO	JG17L-F5AK		JG17L-F5AKL		
AC power		Two-wire system NC	JG17L-F5AB		JG17L-F5ABL		
	Three-wire System Open/Close						
		Supply voltage	DC10-30V AC90-250V				
	С	urrent consumption	NPN/PNP Transistor 1015mA,DC two-wire \leq 0.8mA,AC \leq 2mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	C	Output voltage drop	NPN/PNP Transistor ≤ 1.5V,DC two-wire ≤ 7V,AC ≤ 8V				
	R	esponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1020Hz				
		Detected object	Metal				
	Housing material		ABS Resin				
	A	mbient temperature		-25~	70 ℃		
	In	sulation resistance		≥30	0Μ Ω		
		Protection degree		IP	67		



JR48L/JR54L-L Inductive Proximity Sensor

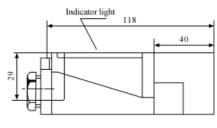


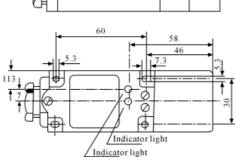


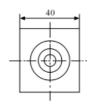
Detected Distance Sn				20mm		25mm		
	Setting Distance Sn			0-16mm		0-20mm		
	Stand	dard Detected A3 Steel		$75\times75\times1\text{mm}^3$		$75 \times 75 \times 1 \text{mm}^3$		
		Installation mode		Not flush Type		Not flush Type		
		NO		JR48L-Y20NK		JR54L-Y25NK		
	NPN	NC		JR48L-Y20NB		JR54L-Y25NB		
		NO/NC		JR48L-Y20NH		JR54L-Y25NH		
DC		NO		JR48L-Y20PK		JR54L-Y25PK		
power	PNP	NC		JR48L-Y20PB		JR54L-Y25PB		
		NO/NC		JR48L-Y20PH		JR54L-Y25PH		
		Two-wire system NO		JR48L-Y20TK		JR54L-Y25TK		
		Two-wire system NC		JR48L-Y20TB		JR54L-Y25TB		
4.0		Two-wire system NO		JR48L-Y20AK		JR54L-Y25AK		
AC power		Two-wire system NC		JR48L-Y20AB		JR54L-Y25AB		
	Three-wire System Open/Close							
		Supply voltage			DC10-30V	AC90-250V		
	C	urrent consumption		NPN/PNP Transistor 1015mA,DC two-wire ≤ 0.8mA,AC ≤ 2mA				
		Output current		NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	С	Output voltage drop		NPN/PNP Transistor \leq 1.5V,DC two-wire \leq 7V,AC \leq 8V				
	Re	esponse frequency		NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1020Hz				
		Detected object		Metal				
		Housing material		ABS Resin				
	Aı	mbient temperature		-25~70°C				
Insulation resistance				≥30M Ω				
		Protection degree			IP	67		
			А	48		54		
	Outsid	le dimensions(mm)	В	62		70		
			С	32		35		



JG40L-Z Inductive Proximity Sensor







	Detected Distance Sn		15mm		20mm		
	Setting Distance Sn		0-12mm		0-16mm		
	Stan	dard Detected A3 Steel	$60 \times 60 \times 1 \text{mm}^3$		$60 \times 60 \times 1 \text{mm}^3$		
		Installation mode	Flush Type		Not flush Type		
		NO	JG40L-Z20NK		JG40L-Z20NK		
	NPN	NC	JG40L-Z20NB		JG40L-Z20NB		
		NO/NC	JG40L-Z20NH		JG40L-Z20NH		
DC		NO	JG40L-Z20PK		JG40L-Z20PK		
power	PNP	NC	JG40L-Z20PB		JG40L-Z20PB		
		NO/NC	JG40L-Z20PH		JG40L-Z20PH		
		Two-wire system NO	JG40L-Z20TK		JG40L-Z20TK		
		Two-wire system NC	JG40L-Z20TB		JG40L-Z20TB		
		Two-wire system NO	JG40L-Z20AK		JG40L-Z20AK		
AC power	Two-wire system NC		JG40L-Z20AB		JG40L-Z20AB		
	Three-wire System Open/Close						
		Supply voltage	DC10-30V AC90-250V				
	С	current consumption	NPN/PNP Transistor 1015mA,DC two-wire \leq 0.8mA,AC \leq 2mA				
		Output current	NPN/PNP Transistor ≤ 200mA,DC two-wire6080mA,AC ≤ 300mA				
	C	Output voltage drop	NPN/PNP Transistor ≤ 1.5V,DC two-wire ≤ 7V,AC ≤ 8V				
	R	esponse frequency	NPN/PNP Transistor400800Hz,DC two-wire200Hz,AC1020Hz				
	Detected object		Metal				
		Housing material	ABS Resin				
	Α	mbient temperature	-25~70°C				
	lr	nsulation resistance	≥30M Ω				
		Protection degree		IP	67		